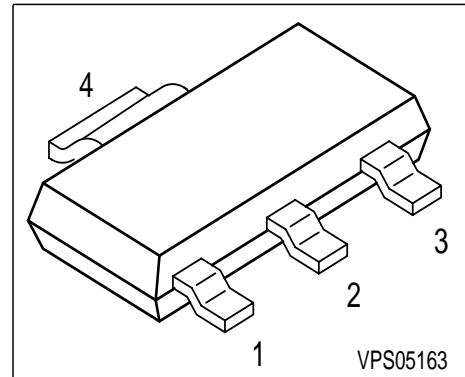


## BCP54...BCP56

- For AF driver and output stages
- High collector current
- Low collector-emitter saturation voltage
- Complementary types: BCP51 ... BCP53 (PNP)



Type	Marking	Pin Configuration				Package
BCP54	BCP 54	1 = B	2 = C	3 = E	4 = C	SOT223
BCP54-10	BCP 54-10	1 = B	2 = C	3 = E	4 = C	SOT223
BCP54-16	BCP 54-16	1 = B	2 = C	3 = E	4 = C	SOT223
BCP55	BCP 55	1 = B	2 = C	3 = E	4 = C	SOT223
BCP55-10	BCP 55-10	1 = B	2 = C	3 = E	4 = C	SOT223
BCP55-16	BCP 55-16	1 = B	2 = C	3 = E	4 = C	SOT223
BCP56-10	BCP 56-10	1 = B	2 = C	3 = E	4 = C	SOT223
BCP56-16	BCP 56	1 = B	2 = C	3 = E	4 = C	SOT223

**Maximum Ratings**

Parameter	Symbol	BCP54	BCP55	BCP56	Unit
Collector-emitter voltage	$V_{CEO}$	45	60	80	V
Collector-emitter voltage $R_{BE} \leq 1\text{k}\Omega$	$V_{CER}$	45	60	100	
Collector-base voltage	$V_{CBO}$	45	60	100	
Emitter-base voltage	$V_{EBO}$	5	5	5	
DC collector current	$I_C$	1			A
Peak collector current	$I_{CM}$	1.5			
Base current	$I_B$	100			mA
Peak base current	$I_{BM}$	200			
Total power dissipation, $T_S = 124\text{ }^\circ\text{C}$	$P_{tot}$	1.5			W
Junction temperature	$T_j$	150			$^\circ\text{C}$
Storage temperature	$T_{stg}$	-65 ... 150			

**Thermal Resistance**

Junction - soldering point <sup>1)</sup>	$R_{thJS}$	$\leq 17$	K/W
--	------------	-----------	-----

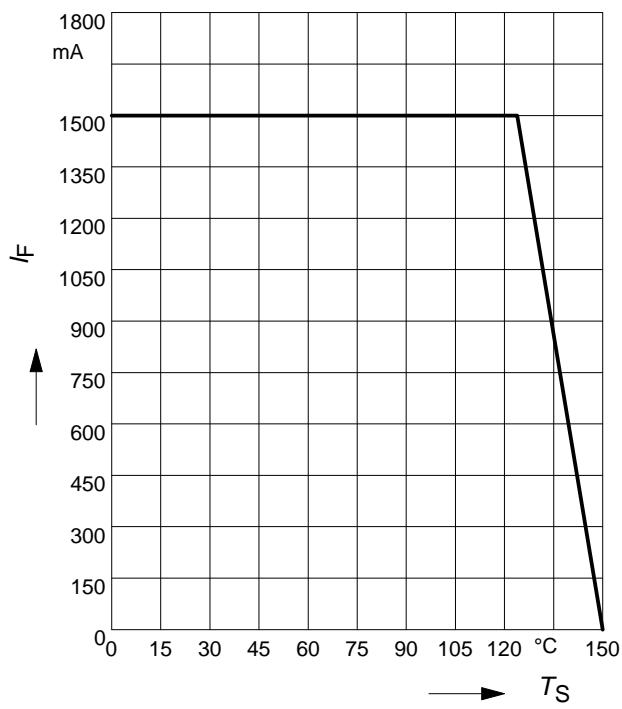
<sup>1</sup>For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance

**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC Characteristics</b>					
Collector-emitter breakdown voltage $I_C = 10 \text{ mA}, I_B = 0$	$V_{(\text{BR})\text{CEO}}$ BCP54	45	-	-	V
		60	-	-	
		80	-	-	
Collector-base breakdown voltage $I_C = 100 \mu\text{A}, I_E = 0$	$V_{(\text{BR})\text{CBO}}$ BCP54	45	-	-	
		60	-	-	
		100	-	-	
Emitter-base breakdown voltage $I_E = 10 \mu\text{A}, I_C = 0$	$V_{(\text{BR})\text{EBO}}$	5	-	-	
		-	-	-	
Collector cutoff current $V_{CB} = 30 \text{ V}, I_E = 0$	$I_{\text{CBO}}$	-	-	100	nA
Collector cutoff current $V_{CB} = 30 \text{ V}, I_E = 0, T_A = 150^\circ\text{C}$	$I_{\text{CBO}}$	-	-	20	μA
DC current gain 1) $I_C = 5 \text{ mA}, V_{CE} = 2 \text{ V}$	$h_{\text{FE}}$	25	-	-	
		40	-	250	
		63	100	160	
DC current gain 1) $I_C = 150 \text{ mA}, V_{CE} = 2 \text{ V}$	$h_{\text{FE}}$ BCP54...56 hFE-grp.10 hFE-grp.16	100	160	250	
		25	-	-	
		-	-	-	
DC current gain 1) $I_C = 500 \text{ mA}, V_{CE} = 2 \text{ V}$	$h_{\text{FE}}$	-	-	0.5	V
		-	-	-	
Collector-emitter saturation voltage1) $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$	$V_{\text{CEsat}}$	-	-	1	
Base-emitter voltage 1) $I_C = 500 \text{ mA}, V_{CE} = 2 \text{ V}$	$V_{\text{BE}(\text{ON})}$	-	-	-	
<b>AC Characteristics</b>					
Transition frequency $I_C = 50 \text{ mA}, V_{CE} = 10 \text{ V}, f = 100 \text{ MHz}$	$f_T$	-	100	-	MHz

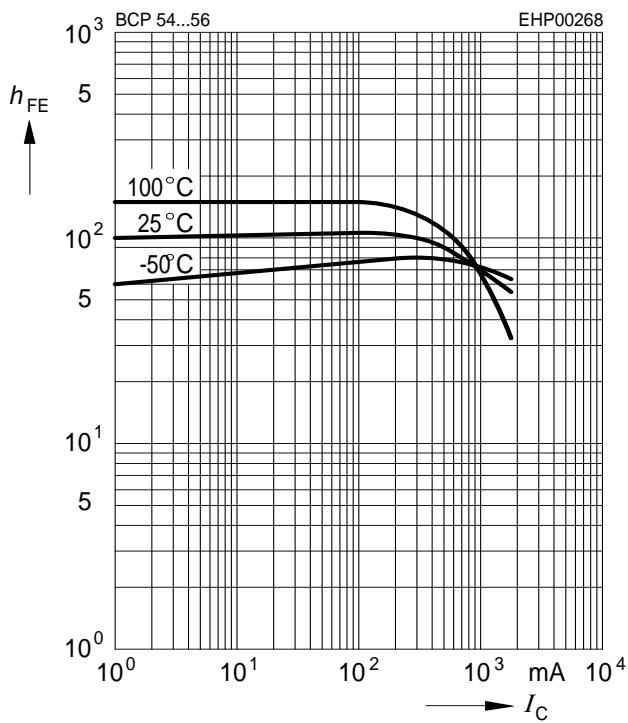
1) Pulse test:  $t \leq 300 \mu\text{s}$ ,  $D = 2\%$

**Total power dissipation**  $P_{\text{tot}} = f(T_S)$



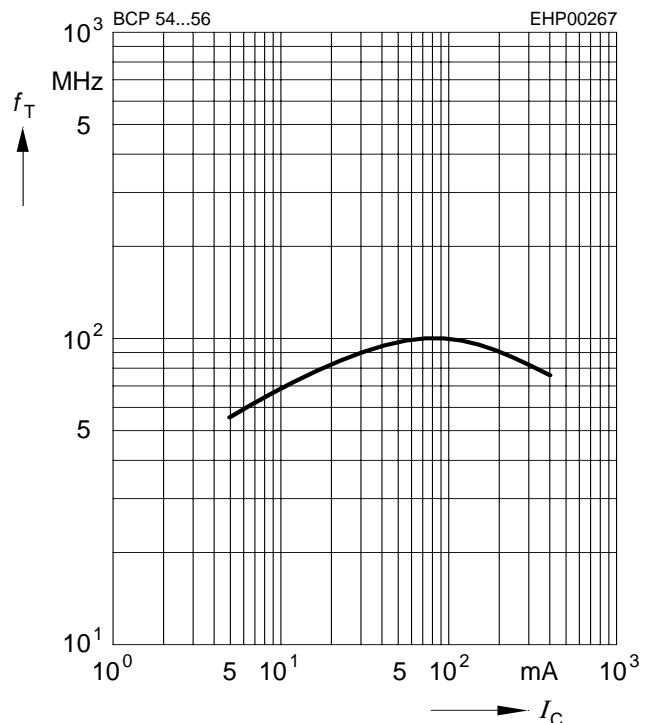
**DC current gain**  $h_{\text{FE}} = f(I_C)$

$V_{\text{CE}} = 2\text{V}$



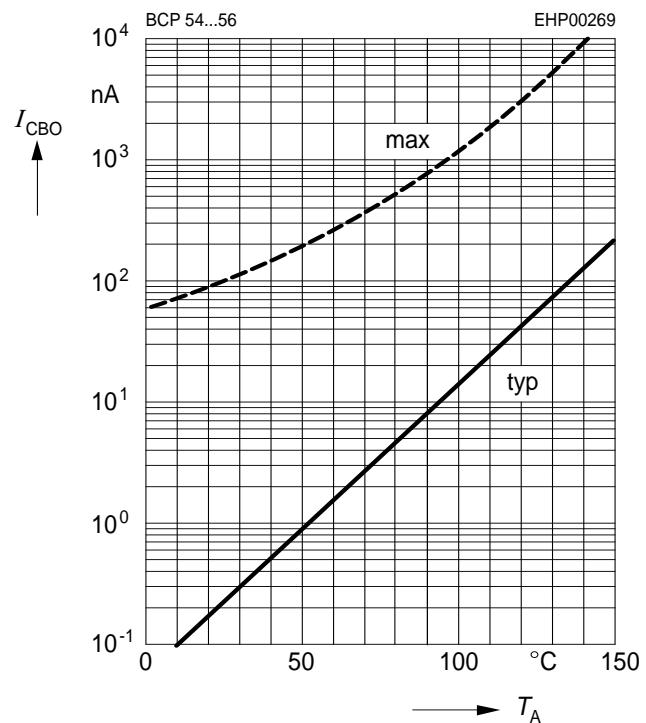
**Transition frequency**  $f_T = f(I_C)$

$V_{\text{CE}} = 10\text{V}$



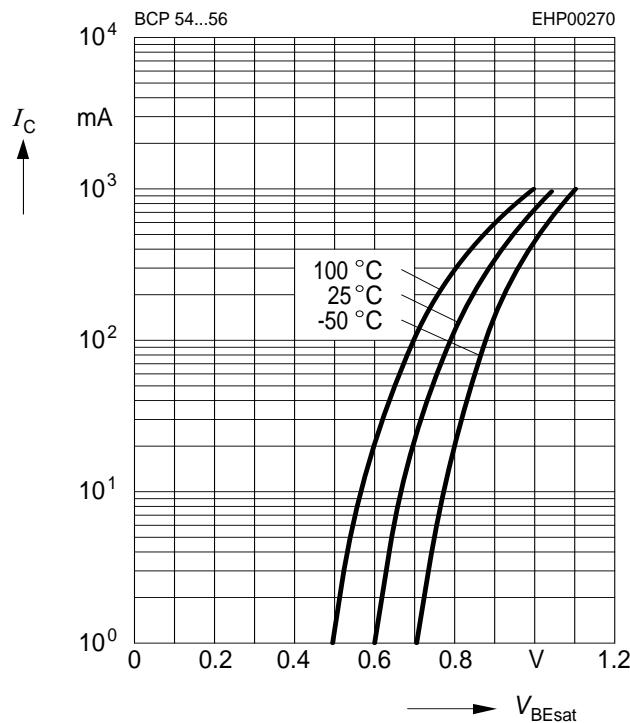
**Collector cutoff current**  $I_{\text{CBO}} = f(T_A)$

$V_{\text{CB}} = 30\text{V}$



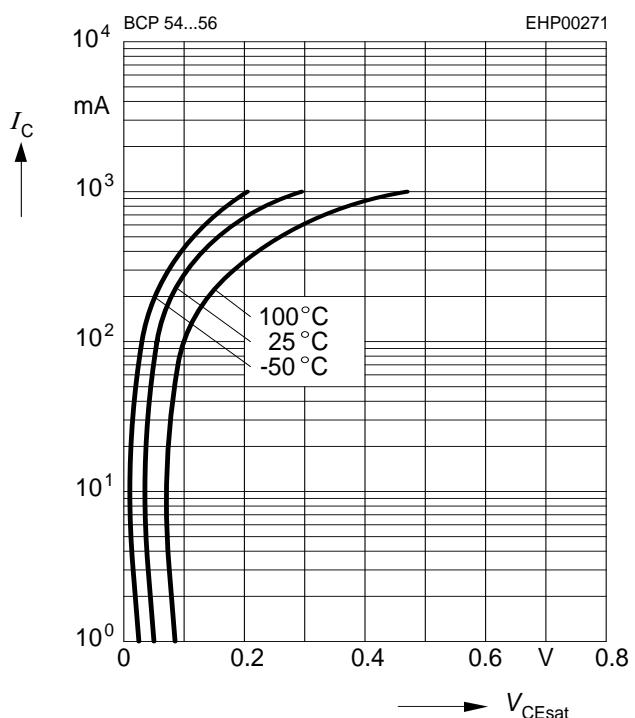
### Base-emitter saturation voltage

$$I_C = f(V_{BEsat}), h_{FE} = 10$$



### Collector-emitter saturation voltage

$$I_C = f(V_{CEsat}), h_{FE} = 10$$



### Permissible pulse load

$$P_{totmax} / P_{totDC} = f(t_p)$$

